

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-6.0	V
Continuous Collector Current	I _C	-100	mA
Peak Pulse Collector Current	I _{CM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

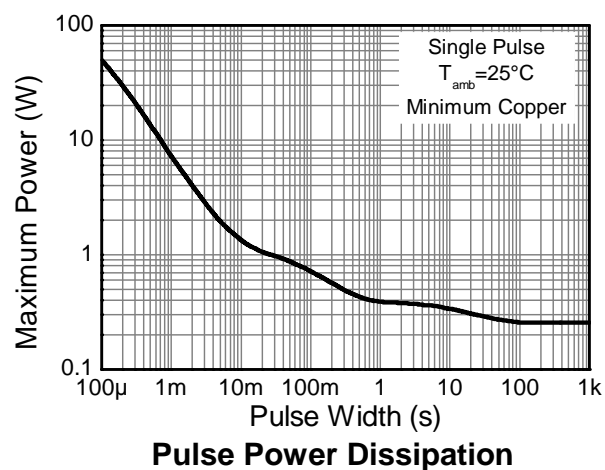
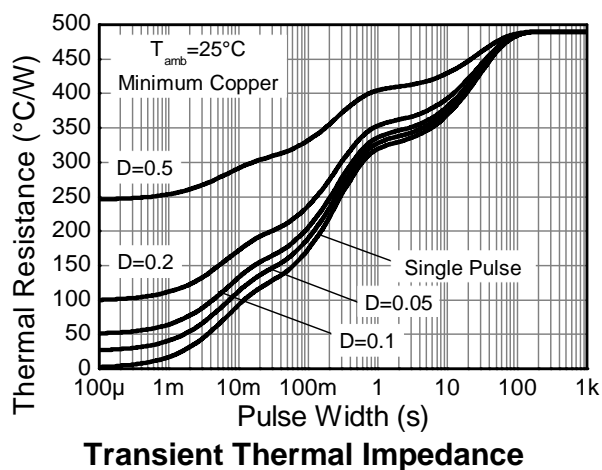
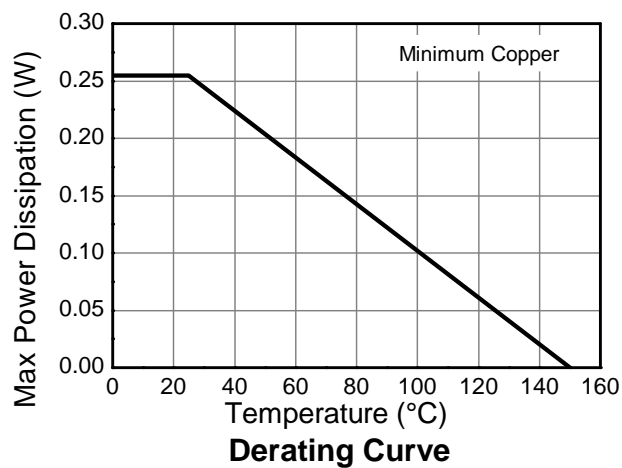
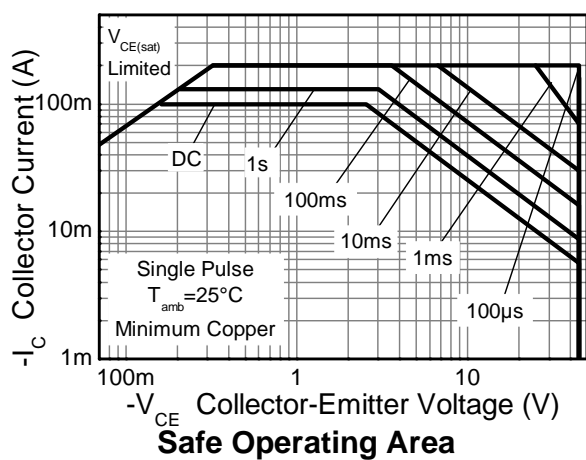
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	270	mW
		925	
Thermal Resistance, Junction to Ambient	R _{θJA}	465	°C/W
		135	
Thermal Resistance, Junction to Lead	R _{θJL}	135	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	200	V	B

- Notes:
5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.
 6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typical	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-100	—	V	I _C = -50μA, I _B = 0
Collector-Emitter Breakdown Voltage	BV _{CES}	-50	-90	—	V	I _C = -50μA, I _B = 0
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-45	-65	—	V	I _C = -1mA, I _B = 0
Collector-Base Breakdown Voltage	BV _{EBO}	-6.0	-8.5	—	V	I _E = -50μA, I _C = 0
Collector-Base Cutoff Current	I _{CBO}	—	—	-15	nA	V _{CB} = -40V
Collector-Emitter Cutoff Current	I _{CES}	—	—	-15	nA	V _{CE} = -40V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	— 200	340 330	— 470	—	I _C = -10μA, V _{CE} = -5.0V I _C = -2.0mA, V _{CE} = -5.0V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	-70 -300	-175 -500	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5.0mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	-760 -885	-1,000 -1,100	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5.0mA
Base-Emitter Voltage	V _{BE(on)}	-600 —	-670 -715	-780 -850	mV	I _C = -2.0mA, V _{CE} = -5V I _C = -10mA, V _{CE} = -5V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	—	2.0	—	pF	V _{CB} = -10.0V, f = 1.0MHz, I _E = 0
Current Gain-Bandwidth Product	f _T	100	270	—	MHz	V _{CE} = -5V, I _C = -10mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

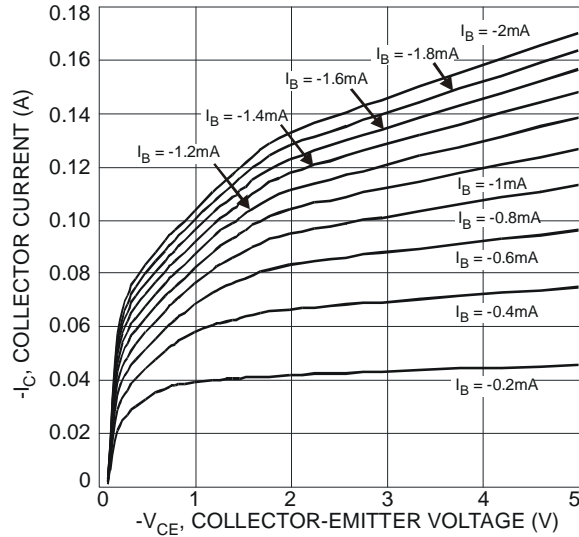


Fig. 4 Typical Collector Current vs. Collector-Emitter Voltage

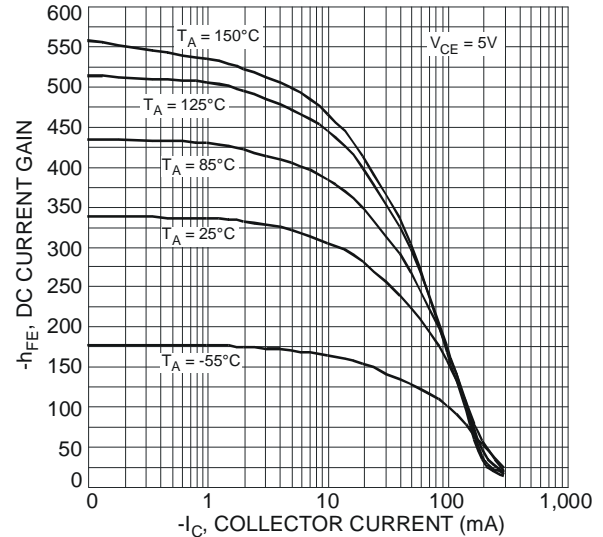


Fig. 5 Typical DC Current Gain vs. Collector Current

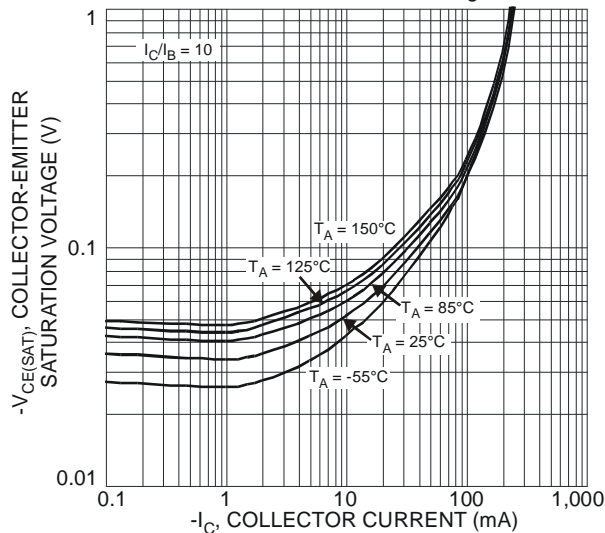


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

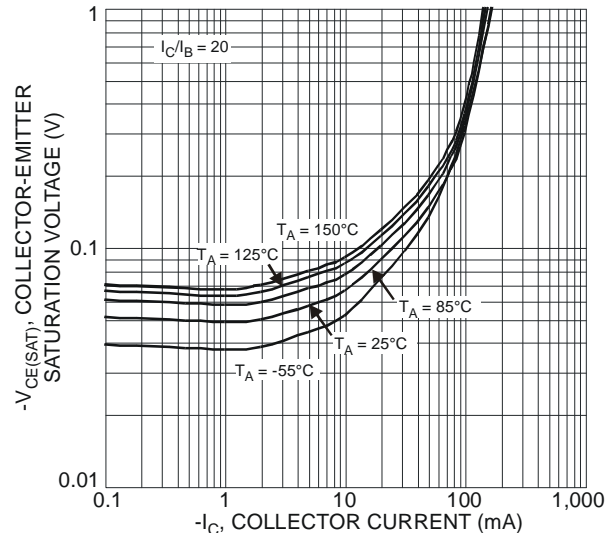


Fig. 7 Typical Collector-Emitter Saturation Voltage vs. Collector Current

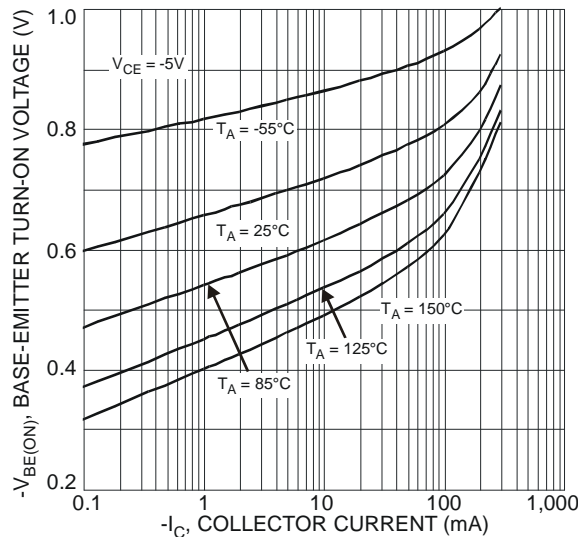


Fig. 8 Typical Base-Emitter Turn-On Voltage vs. Collector Current

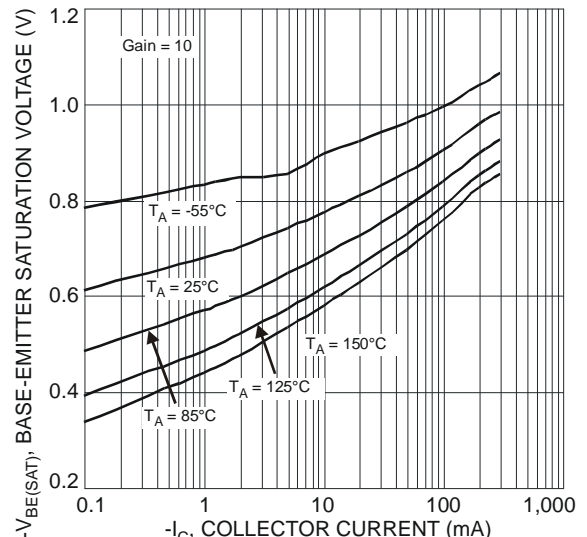
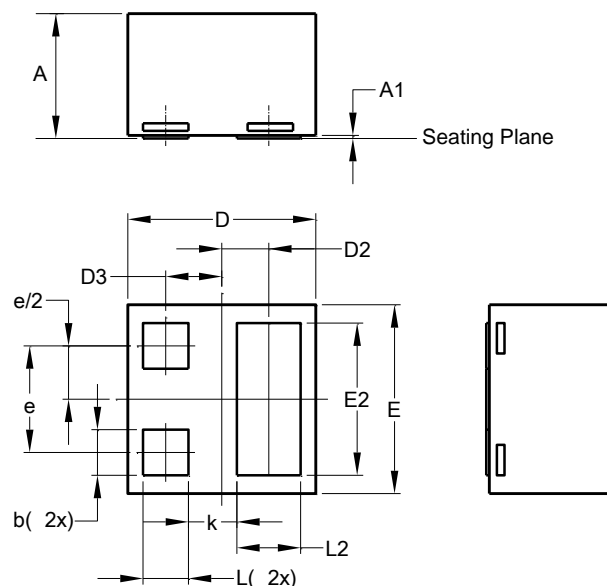


Fig. 9 Typical Base-Emitter Saturation Voltage vs. Collector Current

Package Outline Dimensions

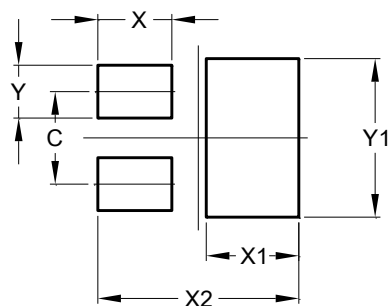
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



X2-DFN0606-3			
Dim	Min	Max	Typ
A	0.36	0.42	0.39
A1	0	0.05	0.02
b	0.10	0.20	0.15
D	0.57	0.67	0.62
D2	0.155 BSC		
D3	0.185 BSC		
E	0.57	0.67	0.62
E2	0.40	0.60	0.50
e	0.35 BSC		
k	0.16 REF		
L	0.09	0.21	0.15
L2	0.11	0.31	0.21
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	0.350
X	0.280
X1	0.350
X2	0.760
Y	0.200
Y1	0.600

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